L Number	Hits	Search Text	DB	Time stamp
-	129	((pores porosity porous asperous asperosity rough\$6) with	USPAT;	2004/04/03 09:20
		(cathode anode electrode)) and 313/500-512.ccls.	US-PGPUB	, , , == == == == == == == == == == = = = = =
-	5	5929561.URPN.	USPAT	2004/03/31 16:51
-	177	((region portion element layer film medium member light) with (EL	USPAT;	2004/03/31 17:16
		electro\$luminescen\$2 emissive emitting emitter emission emits)	US-PGPUB	
		with (pores porosity porous asperous asperosity rough\$6)) and		
		(313/500-512.ccls. 428/690.ccls.)		
-	180	((region portion element layer film medium member light) with (EL	USPAT;	2004/03/31 17:17
		electro\$luminescen\$2 emissive emitting ((charge hole) near3	US-PGPUB	
		(transfer\$3 transport\$3)) emitter emission emits) with (pores		
		porosity porous asperous asperosity rough\$6)) and		
	101	(313/500-512.ccls. 428/690.ccls.)	LICOAT	2004/02/24 47 77
-	181	((region portion element layer film medium member light) with (EL	USPAT;	2004/03/31 17:29
		electro\$luminescen\$2 emissive emitting ((charge electron hole)	US-PGPUB	
1		near3 (transfer\$3 transport\$3)) emitter emission emits) with		
		(pores porosity porous asperous asperosity rough\$6)) and (313/500-512.ccls. 428/690.ccls.)		
-	76	(((region portion element layer film medium member light) with	USPAT;	2004/03/31 17:18
	,,	((LEL electros)luminescen\$2 emissive emitting ((charge electron	US-PGPUB	2007/03/31 17.10
]		hole) near3 (transfer\$3 transport\$3)) emitter emission emits) with	33 / 31 00	
		(pores porosity porous asperous asperosity rough\$6)) and		
		(313/500-512.ccls. 428/690.ccls.)) not @ad>20001005		
-	3	("3819973"   "5469020"   "5485355").PN.	USPAT	2004/03/31 17:24
-	7	5869930.URPN.	USPAT	2004/03/31 17:24
-	2437	((region portion element layer film medium member light) with (EL	EPO; JPO;	2004/03/31 17:29
		electro\$luminescen\$2 emissive emitting ((charge electron hole)	DERWENT	
		near3 (transfer\$3 transport\$3)) emitter emission emits) with		
		(pores porosity porous asperous asperosity rough\$6))		
-	1033	((region portion element layer film medium member light) with (EL	EPO; JPO;	2004/03/31 17:30
		electro\$luminescen\$2 emissive emitting ((charge electron hole)	DERWENT	
		near3 (transfer\$3 transport\$3)) emitter emission emits) with		
		(pores porosity porous asperous asperosity rough\$6)) and (display		
	828	device panel) ((/region portion element layer film medium member light) = ===4	EDO: 300	2004/02/24 17 21
-	٥ <b>2</b> ٥	(((region portion element layer film medium member light) near4 (EL electro\$luminescen\$2 emissive emitting ((charge electron)	EPO; JPO;	2004/03/31 17:31
		hole) near3 (transfer\$3 transport\$3)) emitter emission emits))	DERWENT	
		with (pores porosity porous asperous asperosity rough\$6)) and		
		(display device panel)		
-	341	(((region portion element layer film medium member light) near4	EPO; JPO;	2004/03/31 17:37
		(EL electro\$luminescen\$2 emissive emitting ((charge electron	DERWENT	200 1/03/31 17.37
1		hole) near3 (transfer\$3 transport\$3)) emitter emission emits))		
		with (pores porosity porous asperous asperosity rough\$6)) and		
		((display device panel) near3 (EL electro\$luminescen\$2 OLED		
		(light near3 (emitting emitter emission emissive))))		
-	171		EPO; JPO;	2004/03/31 17:59
		(EL electro\$luminescen\$2 emissive emitting ((charge electron	DERWENT	
		hole) near3 (transfer\$3 transport\$3)) emitter emission emits))	•	
		with (surface superficie) with (pores porosity porous asperous		
	İ	asperosity rough\$6)) and ((display device panel) near3 (EL	•	
		electro\$luminescen\$2 OLED (light near3 (emitting emitter		
_	,	emission emissive))))	DEDWENT	2004/02/24 47 44
<u> </u>	1	1995-218659.NRAN. 1999-410108.NRAN.	DERWENT	2004/03/31 17:44
_	356	(((region portion element layer film medium member light) near4	DERWENT	2004/03/31 17:51
	220	((LE electros) luminescen\$2 emissive emitting ((charge electron	USPAT; US-PGPUB	2004/03/31 18:00
		hole) near3 (transfer\$3 transport\$3)) emitter emission emits))	U3-FGFUD	
		with (surface superficie) with (pores porosity porous asperous		
		asperosity rough\$6)) and ((display device panel) near3 (EL		
		electro\$luminescen\$2 OLED (light near3 (emitting emitter		
		emission emissive))))		

-	7218	(((region portion element layer film medium member light) near4 (EL electro\$luminescen\$2 emissive emitting ((charge electron hole) near3 (transfer\$3 transport\$3)) emitter emission emits)) with (distribution concentration amount)) and ((display device panel) near3 (EL electro\$luminescen\$2 OLED (light near3 (emitting emitter emission emission))))	USPAT; US-PGPUB	2004/03/31 18:02
-	1084	(emitting emitter emission emissive)))) (((region portion element layer film medium member light) near4 (EL electro\$luminescen\$2 emissive emitting ((charge electron hole) near3 (transfer\$3 transport\$3)) emitter emission emits)) with (distribution concentration amount)) and (313/500-512.ccls. 428/690.ccls.)	USPAT; US-PGPUB	2004/03/31 18:02
-	642	(((region portion element layer film medium member light) with (EL electro\$luminescen\$2 emissive emitting ((charge electron hole) near3 (transfer\$3 transport\$3)) emitter emission emits)) with (distribution concentration)) and (313/500-512.ccls. 428/690.ccls.)	USPAT; US-PGPUB	2004/03/31 18:03
-	469	(((region portion element layer film medium member light) with (EL electro\$luminescen\$2 emissive emitting ((charge electron hole) near3 (transfer\$3 transport\$3)) emitter emission emits)) with concentration) and (313/500-512.ccls. 428/690.ccls.)	USPAT; US-PGPUB	2004/03/31 18:03
-	469	((((region portion element layer film medium member light) with (EL electro\$luminescen\$2 emissive emitting ((charge electron hole) near3 (transfer\$3 transport\$3)) emitter emission emits)) with concentration) and (313/500-512.ccls. 428/690.ccls.)	USPAT; US-PGPUB	2004/04/01 11:27
-	380	(((region portion element layer film medium member light) with (EL electro\$luminescen\$2 emissive emitting ((charge electron hole) near3 (transfer\$3 transport\$3)) emitter emission emits)) with concentration) and (313/502-504.ccls. 428/690.ccls.)	USPAT; US-PGPUB	2004/04/01 11:28
-	335	(((region portion element layer film medium member light) with (EL electro\$luminescen\$2 emissive emitting ((charge electron hole) near3 (transfer\$3 transport\$3)) emitter emission emits)) with concentration) and organic and (313/502-504.ccls. 428/690.ccls.)	USPAT; US-PGPUB	2004/04/01 15:45
-	8	"04357694" "11074083" "07235378" "08279628"	EPO; JPO; DERWENT	2004/04/01 11:29
-	20	(((region portion element layer film medium member light) with (EL electrosluminescen\$2 emissive emitting ((charge electron hole) near3 (transfer\$3 transport\$3)) emitter emission emits)) with concentration with gradient) and organic and	USPAT; US-PGPUB	2004/04/01 15:47
_	27	(313/502-504.ccls. 428/690.ccls.) (((region portion element layer film medium member light) with (EL electro\$luminescen\$2 emissive emitting ((charge electron hole) near3 (transfer\$3 transport\$3)) emitter emission emits)) with concentration with gradient) and (313/500-512.ccls.	USPAT; US-PGPUB	2004/04/01 16:47
-	97	428/690.ccls.)  (((region portion element layer film medium member light) with  (EL luminescen\$3 electro\$luminescen\$2 emissive emitting  ((charge electron hole) near3 (transfer\$3 transport\$3)) emitter  emission emits)) with concentration with gradient)	EPO; JPO; DERWENT	2004/04/01 16:48
-	223	(((region portion element layer film medium member light) with (EL luminescen\$3 electro\$luminescen\$2 emissive emitting ((charge electron hole) near3 (transfer\$3 transport\$3)) emitter emission emits)) with concentration with gradient)	USPAT; US-PGPUB	2004/04/01 17:16
-	67	((region portion element layer film member medium matrix) with (EL electro\$luminescen\$2 emission emitting emissive emit emitter organic ((hole charge electron) near3 (transport\$3 transfer\$3))) with concentration with (graded gradient grading rate distribution)) and (313/500-512.ccls. 428/690.ccls.)	USPAT; US-PGPUB	2004/04/01 17:31
-	40	(((region portion element layer film member medium matrix) with (EL electro\$luminescen\$2 emission emitting emissive emit emitter organic ((hole charge electron) near3 (transport\$3 transfer\$3))) with concentration with (graded gradient grading rate distribution)) and (313/500-512.ccls. 428/690.ccls.)) not @ad>20001005	USPAT; US-PGPUB	2004/04/01 17:31

-	47	((region portion element layer film member medium matrix) with (EL electro\$luminescen\$2 emission emitting emissive emit emitter organic ((hole charge electron) near3 (transport\$3 transfer\$3))) with concentration with (variation varying vary varies change	USPAT; US-PGPUB	2004/04/01 17:35
-	30	changing)) and (313/500-512.ccls. 428/690.ccls.) (((region portion element layer film member medium matrix) with	USPAT;	2004/04/01 18:03
		(EL electro\$luminescen\$2 emission emitting emissive emit emitter organic ((hole charge electron) near3 (transport\$3 transfer\$3))) with concentration with (variation varying vary varies change changing)) and (313/500-512.ccls. 428/690.ccls.)) not @ad>20001005	US-PGPUB	
-	613	((region portion element layer film member medium matrix) with (EL electro\$luminescen\$2 emission emitting emissive emit emitter organic ((hole charge electron) near3 (transport\$3 transfer\$3))) with concentration with (graded gradient grading rate distribution	EPO; JPO; DERWENT	2004/04/01 17:35
-	231	variation varying vary varies change changing)) ((region portion element layer film member medium matrix) with (EL electro\$luminescen\$2 emission emitting emissive emit emitter organic ((hole charge electron) near3 (transport\$3 transfer\$3))) with concentration with (graded gradient grading rate distribution variation varying vary varies change changing)) and (display	EPO; JPO; DERWENT	2004/04/01 17:38
-	48	device panel) ((region portion element layer film member medium matrix) with (EL electro\$luminescen\$2 emission emitting emissive emit emitter organic ((hole charge electron) near3 (transport\$3 transfer\$3))) with concentration with (graded gradient grading rate distribution variation varying vary varies change changing)) and (display	EPO; JPO; DERWENT	2004/04/01 17:45
_	1	device panel) and (electrode cathode anode) 2004-076874.NRAN.	DERWENT	2004/04/01 17:44
-	134	((region portion element layer film member medium matrix) same (EL electro\$luminescen\$2 emission emitting emissive emit emitter organic ((hole charge electron) near3 (transport\$3 transfer\$3))) same concentration same (graded gradient grading rate distribution variation varying vary varies change changing)) and (display device panel) and (electrode cathode anode)	EPO; JPO; DERWENT	2004/04/01 17:46
	138	((region portion element layer material dopant doping doped film member medium matrix) same (EL electro\$luminescen\$2 emission emitting emissive emit emitter organic ((hole charge electron) near3 (transport\$3 transfer\$3))) same concentration same (graded gradient grading rate distribution variation varying vary varies change changing)) and (display device panel) and	EPO; JPO; DERWENT	2004/04/01 18:01
-	90	(electrode cathode anode) (((region portion element layer material dopant doping doped film member medium matrix) same (EL electro\$luminescen\$2 emission emitting emissive emit emitter organic ((hole charge electron) near3 (transport\$3 transfer\$3))) same concentration same (graded gradient grading rate distribution variation varying vary varies change changing)) and (display device panel) and (electrode cathode anode)) not (((region portion element layer film member medium matrix) with (EL electro\$luminescen\$2 emission emitting emissive emit emitter organic ((hole charge)	EPO; JPO; DERWENT	2004/04/01 17:47
	282	electron) near3 (transport\$3 transfer\$3))) with concentration with (graded gradient grading rate distribution variation varying vary varies change changing)) and (display device panel) and (electrode cathode anode)) ((region portion element layer material dopant doping doped film	LICDAT•	2004/04/01 19:02
-	282	(region portion element layer material dopant doping doped film member medium matrix) same (EL active electro\$luminescen\$2 emission emitting emissive emit emitter organic ((hole charge electron) near3 (transport\$3 transfer\$3))) same concentration same (graded gradient grading rate distribution variation varying vary varies change changing)) and (display device panel) and (electrode cathode anode) and (313/500-512.ccls. 428/690.ccls.)	USPAT; US-PGPUB	2004/04/01 18:02

-	165	(((region portion element layer material dopant doping doped film	USPAT;	2004/04/02 11:43
		member medium matrix) same (EL active electro\$luminescen\$2	US-PGPUB	
		emission emitting emissive emit emitter organic ((hole charge		
		electron) near3 (transport\$3 transfer\$3))) same concentration		
		same (graded gradient grading rate distribution variation varying		
		vary varies change changing)) and (display device panel) and		
		(electrode cathode anode) and (313/500-512.ccls. 428/690.ccls.))		
	_	not @ad>20001005		2004/04/02 44 47
-	7	("5429884"   "5739635"   "5773929"   "5776622"   "5776623"	USPAT	2004/04/02 11:17
		"5909081"   "5920080").PN.		2004/04/02 44 40
-	8	6064151.URPN.	USPAT	2004/04/02 11:18
-	56	((graded gradient grading distribution variation varying vary varies	USPAT;	2004/04/02 12:45
		change changing) with ((charge hole electron) near3 (transport\$3	US-PGPUB	
		transfer\$3)) with (diffus\$3 concentration amount dopant doping	]	
		doped)) and (313/500-512.ccls. 428/690.ccls.) and (electrode anode cathode)		
_	57	((graded gradient grading distribution variation varying vary varies	EPO; JPO;	2004/04/02 12:49
-	3/	change changing) with ((charge hole electron) near3 (transport\$3	DERWENT	2004/04/02 12.49
		transfer\$3)) with (diffus\$3 concentration amount dopant doping	DERVIENT	
		doped)) and (electrode anode cathode)		
_	175	((graded gradient grading distribution variation density varying	EPO; JPO;	2004/04/02 12:50
	1/3	vary varies change changing) same ((charge hole electron) near3	DERWENT	200 1/0 1/02 12.50
		(transport\$3 transfer\$3)) same (diffus\$3 concentration amount	DERWEIT	
		dopant doping doped)) and (electrode anode cathode)		
_	118	(((graded gradient grading distribution variation density varying	EPO; JPO;	2004/04/02 12:50
		vary varies change changing) same ((charge hole electron) near3	DERWENT	
		(transport\$3 transfer\$3)) same (diffus\$3 concentration amount		
		dopant doping doped)) and (electrode anode cathode)) not		ļ
		(((graded gradient grading distribution variation varying vary		
		varies change changing) with ((charge hole electron) near3		
		(transport\$3 transfer\$3)) with (diffus\$3 concentration amount		
		dopant doping doped)) and (electrode anode cathode))		
-	94	(((charge hole electron) near3 (transfer\$3 transport\$3) near3	USPAT;	2004/04/02 14:30
		(material dopant doped doping medium particle material)) same	US-PGPUB	4
		((luminescen\$3 emitter emission emissive emitting) near3 (dopant		
		doped doping medium particle material)) same (matrix medium))		
		and 428/690.ccls.		
-	87	(((charge hole) near3 (transfer\$3 transport\$3) near3 (material	USPAT;	2004/04/02 14:33
		dopant doped doping medium particle material)) same	US-PGPUB	
		((luminescen\$3 emitter emission emissive emitting) near3 (dopant		
		doped doping medium particle material)) same (matrix medium)) and 428/690.ccls.		
_	97		USPAT;	2004/04/02 14:47
	"	dopant doped doping medium particle material)) same	US-PGPUB	2007/07/02 17.7/
		((luminescen\$3 emitter emission emissive emitting) near3 (dopant	03 1 01 05	
		doped doping medium particle material)) same (matrix medium))		
		and 313/503-504.ccls.		
-	10	1	USPAT;	2004/04/02 14:49
		dopant doped doping)) same ((luminescen\$3 emitter emission	US-PGPUB	
		emissive emitting) near3 (diffus\$3 dopant doped doping)) same		
		(matrix medium)) and 313/503-504.ccls.		
-	14		USPAT;	2004/04/02 14:50
		dopant doped doping)) same ((luminescen\$3 emitter emission	US-PGPUB	
		emissive emitting) near5 (diffus\$3 dopant doped doping)) same		
		(matrix medium)) and 428/690.ccls.		
-	0	(((charge hole) near5 (transfer\$3 transport\$3) near3 (diffus\$3	EPO; JPO;	2004/04/02 14:50
		dopant doped penetrat\$3 doping)) same ((luminescen\$3 emitter	DERWENT	
		emission emissive emitting) near5 (diffus\$3 dopant penetrat\$3		
	_	doped doping)) same (matrix medium))		
-	5	(((charge hole) near5 (transfer\$3 transport\$3) near3 (diffus\$3	EPO; JPO;	2004/04/02 14:52
		dopant doped penetrat\$3 doping)) same ((luminescen\$3 emitter	DERWENT	
		emission emissive emitting) near5 (diffus\$3 dopant penetrat\$3		
	1	doped doping)) same (matrix host medium))		<u> </u>

-	8	(((charge electron hole) near5 (transfer\$3 transport\$3) near3 (diffus\$3 dopant doped penetrat\$3 doping)) same ((luminescen\$3	EPO; JPO; DERWENT	2004/04/02 14:53
		emitter emission emissive emitting) near5 (diffus\$3 dopant		
_	9	penetrat\$3 doped doping)) same (matrix host medium)) (((charge electron hole) with (transfer\$3 transport\$3) near3	EPO; JPO;	2004/04/02 14:54
_		(((charge electron hole) with (transfers 5 transports) hears (diffus\$3 dopant doped penetrat\$3 doping)) same ((luminescen\$3	DERWENT	2007/07/02 17.34
		emitter emission emissive emitting) with (diffus\$3 dopant	DERWEIT	
		penetrat\$3 doped doping)) same (matrix host medium))		
_	54	((((charge electron hole) with (transfer\$3 transport\$3) near3	USPAT;	2004/04/02 14:58
	"	(((diffus\$3 dopant doped penetrat\$3 doping)) same ((luminescen\$3	US-PGPUB	200 1/0 1/02 11.50
		emitter emission emissive emitting) with (diffus\$3 dopant	00 1 01 00	
		penetrat\$3 doped doping)) same (matrix host medium))) and		
		313/502-504.ccls.		
-	48	((((charge electron hole) with (transfer\$3 transport\$3) near3	USPAT;	2004/04/02 14:59
		(diffus\$3 dopant doped penetrat\$3 doping)) same ((luminescen\$3	US-PGPUB	
		emitter emission emissive emitting) with (diffus\$3 dopant		
		penetrat\$3 doped doping)) same (matrix host medium))) and		
		428/690.ccls.		
-	199	(((charge electron hole) with (transfer\$3 transport\$3) with	USPAT;	2004/04/02 15:02
		(diffus\$3 dopant doped penetrat\$3 doping)) same ((luminescen\$3	US-PGPUB	
		emitter emission emissive emitting) with (diffus\$3 dopant		
		penetrat\$3 doped doping)) same ((emission emitting emissive emitter active) near3 (film layer region member portion element)))		
		and 428/690.ccls.		
-	258	(((charge electron hole) with (transfer\$3 transport\$3) with	USPAT;	2004/04/02 15:02
		(diffus\$3 dopant doped penetrat\$3 doping)) same ((luminescen\$3	US-PGPUB	200 1/0 1/02 15.02
		emitter emission emissive emitting) with (diffus\$3 dopant	33 / 3. 32	
		penetrat\$3 doped doping)) same ((emission emitting emissive		
		emitter active) near3 (film layer region member portion element)))		
		and 313/502-504.ccls.		
-	96	(((charge electron hole) near3 (transfer\$3 transport\$3) near5	USPAT;	2004/04/02 15:06
		(diffus\$3 dopant doped penetrat\$3 doping)) same ((luminescen\$3	US-PGPUB	
		emitter emission emissive emitting) near5 (diffus\$3 dopant		
		penetrat\$3 doped doping)) same ((emission emitting emissive emitter active) near3 (film layer region member portion element)))		
		and 428/690.ccls.		
-	135	(((charge electron hole) near3 (transfer\$3 transport\$3) near5	USPAT;	2004/04/02 15:08
		(diffus\$3 dopant doped penetrat\$3 doping)) same ((luminescen\$3	US-PGPUB	==== ,, = ,, == ======
		emitter emission emissive emitting) near5 (diffus\$3 dopant		
	,	penetrat\$3 doped doping)) same ((emission emitting emissive		
		emitter active) near3 (film layer region member portion element)))		
		and 313/500-512.ccls.		2004/04/22 := :
<del>-</del>	268	(((charge electron hole) near3 (transfer\$3 transport\$3) near5	USPAT;	2004/04/02 15:11
		(diffus\$3 dopant doped penetrat\$3 doping)) same ((luminescen\$3 phosphor fluorescen\$3 phosphorescen\$3 photo\$luminescen\$3	US-PGPUB	
		luminophor fluorophor emitter emission emissive emitting) near5		
		(diffus\$3 dopant penetrat\$3 doped doping)) same (((emission		
		emitting emissive emitter active) near3 (film layer region member		
		portion element)) medium matrix host))		
<b>-</b>	25	(((charge electron hole) near3 (transfer\$3 transport\$3) near5	EPO; JPO;	2004/04/02 15:27
		(diffus\$3 dopant doped penetrat\$3 doping)) same ((luminescen\$3	DERWENT	-
		phosphor fluorescen\$3 phosphorescen\$3 photo\$luminescen\$3		
		luminophor fluorophor emitter emission emissive emitting) near5		
		(diffus\$3 dopant penetrat\$3 doped doping)) same (((emission		
		emitting emissive emitter active) near3 (film layer region member portion element)) medium matrix host))		
-	0	6066357.ccls.	USPAT;	2004/04/02 15:28
		0000007.0000.	US-PGPUB	2007/07/02 13.20
_	1	6066357.pn.	USPAT;	2004/04/02 18:10
			US-PGPUB	, - , - =
-	6	("4356429"   "4539507"   "4720432"   "4769292"   "5294869"	USPAT	2004/04/02 15:29
		"5294870").PN.		
-	4	6066357.URPN.	USPAT	2004/04/02 15:29

,		,		
-	2	"04357694"	EPO; JPO;	2004/04/02 18:10
			DERWENT	
-	1	1993-031086.NRAN.	DERWENT	2004/04/02 18:10
-	4	("5151629"   "5755999"   "5804322"   "5834130").PN.	USPAT	2004/04/03 09:27
-	9	5925980.URPN.	USPAT	2004/04/03 09:27
-	24	choong-v\$.in.	EPO; JPO;	2004/04/03 09:59
			DERWENT	
-	6	((electron near3 (transfer\$3 transport\$3)) with (rough\$5 porous	USPAT;	2004/04/03 10:02
		porosity pores)) and 313/500-512.ccls.	US-PGPUB	
-	3	((electron near3 (transfer\$3 transport\$3)) with (rough\$5 porous	USPAT;	2004/04/03 10:03
		porosity pores)) and 428/690.ccls.	US-PGPUB	
_	41	((electron near3 (transfer\$3 transport\$3)) with (rough\$5 porous	EPO; JPO;	2004/04/03 10:06
		porosity pores))	DERWENT	
_	0	((electron near3 (transfer\$3 transport\$3)) with (rough\$5 porous	EPO; JPO;	2004/04/03 10:07
		porosity pores)) and 427/\$.ccls.	DERWENT	====,,==,
-	15	((electron near3 (transfer\$3 transport\$3)) with (rough\$5 porous	USPAT;	2004/04/03 10:08
		porosity pores)) and 427/\$.ccls.	US-PGPUB	==== ., = ., == ===
_	14	((electron near3 (transfer\$3 transport\$3)) with (rough\$5 porous	USPAT;	2004/04/03 10:09
		porosity pores)) and 428/\$.ccls.	US-PGPUB	
_	3	((electron near3 (transfer\$3 transport\$3)) with (rough\$5 porous	USPAT;	2004/04/03 10:09
		porosity pores)) and 445/\$.ccls.	US-PGPUB	
-	13		USPAT;	2004/04/03 10:11
		porosity pores)) and 313/\$.ccls.	US-PGPUB	
-	9	((electron near3 (transfer\$3 transport\$3)) with (rough\$5 porous	USPAT;	2004/04/03 10:11
		porosity pores)) and 438/\$.ccls.	US-PGPUB	, - ,
-	31	((electron near3 (transfer\$3 transport\$3)) with (rough\$5 porous	USPAT;	2004/04/03 10:15
		porosity pores)) and 257/\$.ccls.	US-PGPUB	
-	72	313/500-512.ccls. and ((porous porosity rough\$5 pores) same	USPAT;	2004/04/03 10:27
		(solvent etch\$3))	US-PGPUB	
-	9	313/500-512.ccls. and ((porous porosity rough\$5 pores) same	USPAT;	2004/04/03 10:27
		silicon same (solvent etch\$3))	US-PGPUB	
-	402	427/\$.ccls. and ((porous porosity rough\$5 pores) same silicon	USPAT;	2004/04/03 10:27
		same (solvent etch\$3))	US-PGPUB	
-	2185	438/\$.ccls. and ((porous porosity rough\$5 pores) same silicon	USPAT;	2004/04/03 10:28
		same (solvent etch\$3))	US-PGPUB	
-	871	438/\$.ccls. and ((porous porosity rough\$5 pores) with silicon with	USPAT;	2004/04/03 10:28
		(solvent etch\$3))	US-PGPUB	
-	99	427/\$.ccls. and ((porous porosity rough\$5 pores) with silicon with	USPAT;	2004/04/03 10:29
		(solvent etch\$3))	US-PGPUB	
-	23	313/\$.ccls. and ((porous porosity rough\$5 pores) with silicon with	USPAT;	2004/04/03 10:31
		(solvent etch\$3))	US-PGPUB	
-	1	313/\$.ccls. and ((porous porosity rough\$5 pores) with silicon with	USPAT;	2004/04/03 10:32
		(wet\$etch\$3 (wet near3 etch\$3)))	US-PGPUB	
-	7	428/\$.ccls. and ((porous porosity rough\$5 pores) with silicon with	USPAT;	2004/04/03 10:32
		(wet\$etch\$3 (wet near3 etch\$3)))	US-PGPUB	